

IN THE SPECIFICATION:

Please replace the paragraph beginning at page 40, line 22 with the following amended paragraph:

In the active-matrix organic EL display panel, a plurality of pixels are separated from each other, and a TFT (Thin Film Transistor) circuit comprising a FET (Field Effect Transistor) and a capacitor is provided for each pixel (emission part). Accordingly, as shown in Fig. 9, since display electrodes 12D of the emission part are spread all over the substrate with the gap filling part GF among them, when the electrode is, for example, rectangular, and length of sides are assumed to be L_x, L_y, M_x, M_y , and distances among the display electrodes are assumed to be D_x, D_y , R_{gap} is approximated as the following formula.

$$R_{\text{gap}} = \rho s_{\text{ctl}} / [2 \cdot \{ (M_x / D_y) + (M_y / D_x) \}]$$

... formula (75).